



Article

# Synthesis and Characterization of *p-n* Junction Ternary Mixed Oxides for Photocatalytic Coprocessing of CO<sub>2</sub> and H<sub>2</sub>O

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**Abstract:** In the present paper, we report the synthesis and characterization of both binary (Cu<sub>2</sub>O, Fe<sub>2</sub>O<sub>3</sub>, and In<sub>2</sub>O<sub>3</sub>) and ternary (Cu<sub>2</sub>O-Fe<sub>2</sub>O<sub>3</sub> and Cu<sub>2</sub>O-In<sub>2</sub>O<sub>3</sub>) transition metal mixed-oxides that may find application as photocatalysts for solar driven CO<sub>2</sub> conversion into energy rich species. Two different preparation techniques (High Energy Milling (HEM) and Co-Precipitation (CP)) are compared and materials properties are studied by means of a variety of characterization and analytical techniques UV-Visible Diffuse Reflectance Spectroscopy (UV-VIS DRS), X-ray Photoelectron Spectroscopy (XPS), X-Ray Diffraction (XRD), Transmission Electron Microscopy (TEM), and Energy Dispersive X-Ray spectrometry (EDX). Appropriate data elaboration methods are used to extract materials bandgap for Cu<sub>2</sub>O@Fe<sub>2</sub>O<sub>3</sub> and Cu<sub>2</sub>O@In<sub>2</sub>O<sub>3</sub> prepared by HEM and CP, and foresee whether the newly prepared semiconductor mixed oxides pairs are useful for application in CO<sub>2</sub>-H<sub>2</sub>O coprocessing. The experimental results show that the synthetic technique influences the photoactivity of the materials that can correctly be foreseen on the basis of bandgap experimentally derived. Of the mixed oxides prepared and described in this work, only Cu<sub>2</sub>O@In<sub>2</sub>O<sub>3</sub> shows positive results in CO<sub>2</sub>-H<sub>2</sub>O photo-co-processing. Preliminary results show that the composition and synthetic methodologies of mixed-oxides, the reactor geometry, the way of dispersing the photocatalyst sample, play a key role in the light driven reaction of CO<sub>2</sub>-H<sub>2</sub>O. This work is a rare case of full characterization of photo-materials, using UV-Visible DRS, XPS, XRD, TEM, EDX for the surface and bulk analytical characterization. Surface composition may not be the same of the bulk composition and plays a key role in photocatalysts behavior. We show that a full material knowledge is necessary for the correct forecast of their photocatalytic behavior, inferred from experimentally determined bandgaps.

**Keywords:** CO<sub>2</sub>-H<sub>2</sub>O photo-co-processing; VIS-light driven reactions; CO<sub>2</sub> reduction; photocatalysts properties

## 1. Introduction

Combustion of fossil fuels (fossil-C) is actually the main source (80.2% as for 2018) to fulfil human hunger for energy, but natural resources are not infinite and are expected to get exhausted in 160 y or so. Moreover, the use of fossil-C is responsible for the emission of 37 Gt/y of CO<sub>2</sub> and other green-house gases considered to be the origin of climate change. According to Earth System Research Laboratory's—ESRL's Global Monitoring Laboratory, in January 2020, atmospheric concentration of

CO<sub>2</sub> reached 412 ppm [1]. However, avoiding massive and continuous CO<sub>2</sub> emission and utilization of alternative sustainable primary energy sources is necessary [2]. On the other hand, CO<sub>2</sub> represents a readily available building block for chemicals and source of carbon for fuels, which can be produced through a conversion driven by C-free energy sources [3]. Solar radiations carry a quantity of energy to Earth surface, sufficient to be considered to perform CO<sub>2</sub> conversion [4]. This can be realized by means of photocatalysis [5], in a semiconductor-assisted light-driven process during which light is absorbed and converted into chemical energy, such as CO, CH<sub>3</sub>OH, CH<sub>4</sub>, C<sub>n</sub>-species, or even H<sub>2</sub>, produced in water-splitting [6,7].

Unfortunately, for the moment, the photocatalytic processes still suffer low efficiency and are not ready for an industrial commercially viable application [5], despite the research started with work by T. Inoue [8] and J.M. Lehn [9] that dates back to 40 years ago. Searching for the best photocatalysts [10], a variety of semiconductors have been studied, ranging from those based onto Group 4 elements to more classical Group 3–5 semiconductors [11,12], Group 6 chalcogenides [13] and more “exotic” semiconductors [14]. Among the latter materials, Earth-abundant transition and post-transition metal oxides such as TiO<sub>2</sub>, Fe<sub>2</sub>O<sub>3</sub>, Cu<sub>2</sub>O, CuO, ZnO, NiO, Ta<sub>2</sub>O<sub>5</sub>, Ga<sub>2</sub>O<sub>3</sub>, In<sub>2</sub>O<sub>3</sub>, and WO<sub>3</sub> revealed very promising to act both as photo-catalysts [10–12] or co-catalysts [15]. They are usually cheap and yet widely used as chemo-catalysts in industrial applications, easily fabricated at micro- and nano-size and can absorb light in the UV-Visible region [16,17]. Further, they can be efficiently coupled to enhance properties such as visible light absorption [18], band edge levels’ position, and photogenerated charge transfer, and separation processes [15]. Copper oxides, both CuO and Cu<sub>2</sub>O, were recently demonstrated able to convert CO<sub>2</sub> or water into solar fuels under VIS-light irradiation [19]. These *p-type* semiconductors, that can efficiently be used either bare [20] or as co-catalysts [21–24], are affected by high recombination rate and photodegradation. The formation of a heterojunction by coupling with a suitable *n-type* semiconductor, is a widely adopted strategy to inhibit charge recombination, enhance stability and provide alternative energy levels to carry out photocatalytic reactions [11,12]. The formation of such junctions even at very small particle size is one of the keys for leading to fabrication of active photocatalysts. The semiconductor coupling strategy can also be adopted for copper oxides, in which properties as photostability and charge separation are found to be significantly affected by coupling with *n-type* metal oxides [19]. At the same time, the addition of copper oxides is useful to shift the absorption spectrum of semiconductor partner towards visible range [12,18].

In the present work, two different *n-type* metal oxides were selected as potential partners for Cu<sub>2</sub>O: indium oxide, In<sub>2</sub>O<sub>3</sub>, and iron oxide in the form of hematite,  $\alpha$ -Fe<sub>2</sub>O<sub>3</sub>. Thanks to band energy levels position, affinity towards CO<sub>2</sub> and electronic properties, both these oxides are recognized in literature as potential photocatalysts or cocatalysts for solar fuels production [12,25,26]. In particular, indium oxide has been recently experimented for CH<sub>4</sub> and H<sub>2</sub> photocatalytic production, coupled with other semiconductors or cocatalysts [27,28], or even with a thermal input during the reaction [29,30]. Instead, iron oxide is widely experimented for photocatalytic dye degradation [31] and water cleaning [26], but recently water splitting application is under study [32].

To the best of our knowledge, semiconductor pairs composed of Cu<sub>2</sub>O with In<sub>2</sub>O<sub>3</sub> or  $\alpha$ -Fe<sub>2</sub>O<sub>3</sub> are very scarcely characterized and tested for solar fuels production. Thin films are generally preferred over powders and particles. For the latter, 2D semiconductors as graphene or carbon nitride have been used as platforms for achieving enhanced charge separation and better lattice matching [10–12]. This is especially true for the Cu<sub>2</sub>O-In<sub>2</sub>O<sub>3</sub> pair, where lattice parameters mismatch can hinder the formation of heterojunctions, but samples prepared by hydrothermal/co-precipitation methods are possibly active in photocatalytic degradation and hydrogen evolution [33,34]. In the literature, the Cu<sub>2</sub>O-Fe<sub>2</sub>O<sub>3</sub> pair is reported to a bigger extent than that with Cu<sub>2</sub>O-In<sub>2</sub>O<sub>3</sub> and samples prepared by solvothermal, co-precipitation or electrodeposition methods were tested for photocatalytic degradation [35], hydrogen production [36,37] and CO<sub>2</sub> reduction to carbon monoxide, methanol and methane [38,39]. A point to mention is that the Cu/In,Fe-mixed-oxides were not always fully characterized and often they were

added with other compounds (especially noble metals) and hole scavengers, adding complexity to the already not clearly defined system and making difficult to understand the role of each partner.

In this work, mixed-oxide nano-particles were prepared through two different techniques: High Energy Milling—HEM and Co-Precipitation—CP. Starting oxides were either commercial samples or synthesized in our laboratory. Neat nano-sized powder samples were analyzed by Energy Dispersive X-Ray spectrometry (EDX), characterized by UV-Visible Diffuse Reflectance Spectroscopy (UV-VIS DRS), and X-ray Photoelectron Spectroscopy (XPS) and then tested in gas phase CO<sub>2</sub>–H<sub>2</sub>O co-processing under VIS-light irradiation, at room temperature, without addition of noble metal co-catalysts or hole scavenger species to evaluate the properties of the single mixed oxides. Evaluation and tailoring of properties of cited materials, with particular attention to electronic band structure and optical absorption, was the final goal of this work, targeting a correlation among properties of the materials and their photocatalytic activity in co-processing H<sub>2</sub>O and CO<sub>2</sub> under VIS-light in different reactor geometries.

## 2. Results and Discussion

### 2.1. Synthesis, Composition, and Size of Ternary Oxides

Binary oxides powders used in this work were either commercial samples (C-Oxide) or synthesized in the laboratory (S-Oxide). Ternary oxides powders were fabricated through HEM and CP techniques, as reported in the Materials and Methods section. Such mixed oxides are labelled in Table 1 according to the preparation technique employed and numbered according to increasing Cu/In or Cu/Fe molar ratio, as measured by EDX spectrometry and calculated considering all copper, indium, and iron present in the form of Cu<sub>2</sub>O, In<sub>2</sub>O<sub>3</sub>, and Fe<sub>2</sub>O<sub>3</sub>, respectively.

**Table 1.** Composition of Mixed-Oxide samples prepared by High Energy Milling (HEM) or Co-Precipitation (CP), listed by molar ratio.

Sample Name	Cu/In Ratio	Sample Name	Cu/Fe Ratio
HEM-Cu/In-1	0.60	HEM-Cu/Fe-1	0.59
HEM-Cu/In-2	1.08	HEM-Cu/Fe-2	0.99
HEM-Cu/In-3	2.20	HEM-Cu/Fe-3	1.92
CP-Cu/In-1	0.25	CP-Cu/Fe-1	0.23
CP-Cu/In-2	1.58	CP-Cu/Fe-2	0.66
CP-Cu/In-3	2.96	CP-Cu/Fe-3	1.21

Preliminary Transmission Electron Microscopy (TEM) measurements were carried out on ternary mixed oxides containing Cu<sub>2</sub>O and In<sub>2</sub>O<sub>3</sub>. TEM micrographs show that both techniques (HEM and CP) were able to produce single particles with linear size below 100 nm, which aggregate into sub-micrometric clusters, which show some differences. While in HEM prepared samples, clusters are produced by association of particles upon collision, with relevant presence of amorphous phase and no precise morphology, in CP prepared samples clusters are produced by stacking of well-formed particles of cubic morphology [24], which is common to crystal lattice of both component binary oxides [25,40], and particles clearly show a core-shell coverage.

Powder X-Ray Diffraction (XRD) measurements, used to study crystallinity and crystal phase of selected ternary oxides samples, allowed determine that, while samples prepared by HEM miss any crystallinity, samples prepared by CP show small size crystalline domains, with Cu<sub>2</sub>O is in its usual cubic phase and Fe<sub>2</sub>O<sub>3</sub> in its rhombohedral  $\alpha$  phase (hematite).

### 2.2. XPS Analysis

XPS measurements were carried out onto all single metal oxides and even a set of selected mixed oxides, in order to investigate their surface elemental composition, measured as atomic percentage, with oxidation state speciation. Such a study is fundamental in the present work, for evaluating how

the different preparation techniques influence the properties of the materials. In binary metal oxide samples, regions relative to specific core levels and Auger transitions are here the object for detailed analysis of high resolution XPS spectra.

Copper oxidation state and speciation are commonly studied looking at high resolution spectra for Cu 2p<sub>3/2</sub> core level in the Binding Energy (BE) range 925–950 eV and for Cu L<sub>3</sub>M<sub>4,5</sub>M<sub>4,5</sub> (Cu LMM) Auger transition (BE 555–600 eV). Considerations about peak shape, curve fitting, shake-up peaks and the value of the proper modified Auger parameter are needed [41,42]. The latter equals 1849.0 eV in both commercial (C) and synthesized (S) samples. This value and the inspection of the Auger peak shape exclude any occurrence of Cu metal. Moreover, the lack of shake-up peaks in S-Cu<sub>2</sub>O confirms the almost exclusive presence of the Cu(I) oxidation state for copper atoms, while shake-up peaks observed in C-Cu<sub>2</sub>O, support the presence of CuO [41,42]. These considerations and curve fitting of O 1s XPS peak are used to determine the ratio Cu(I)/Cu(II), that equals 95/5 in S-Cu<sub>2</sub>O and 70/30 in C-Cu<sub>2</sub>O, showing that the surface of commercial Cu<sub>2</sub>O sample is significantly oxidized.

Similar arguments are used for speciation of Indium atoms: analysis involves the In 3d core level doublet (BE 440–460 eV) and the In M<sub>5</sub>N<sub>4,5</sub>N<sub>4,5</sub> (In MNN) Auger transition (BE 1060–1090 eV) [43]. Energy positions of these are used to calculate a proper modified Auger parameter, which equals 850.8 eV in S-In<sub>2</sub>O<sub>3</sub> and 851.1 eV in C-In<sub>2</sub>O<sub>3</sub>. The core level peaks resulted broad and symmetric, and no plasmon loss feature at higher binding energies were observed, as it would be expected if metallic Indium was present [43,44]. It can be thus concluded that In<sub>2</sub>O<sub>3</sub> (both C and S) samples are formed exclusively of In(III)-oxide.

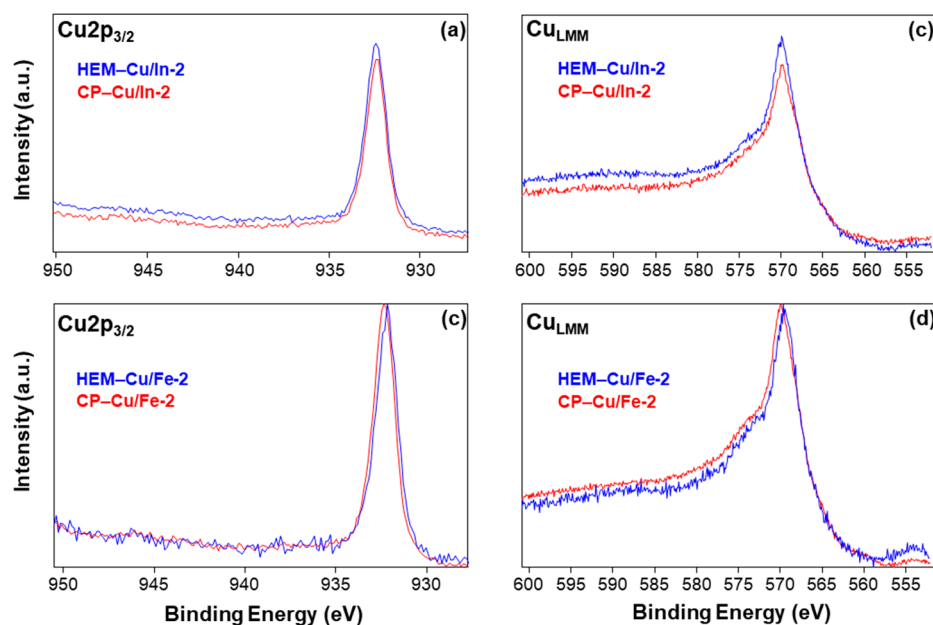
In samples containing iron atoms, the study about the Fe-oxidation state focused onto Fe 2p core level multiplet, occurring in the 705–730 eV region [45,46]. It is recorded as the envelope of different signals coming from electrostatic and spin interactions, from crystal field interactions and from spin-orbit coupling between the 2p and 3d states. This signal requires careful curve fitting operation able to identify the 2p<sub>3/2</sub> main peak center of gravity and satellite peaks structures, due to shake-up and charge transfer processes, whose binding energy separation is used as parameter [45]. The recorded signal indicates that only the Fe<sup>3+</sup> oxidation state is present in the prevalent α-Fe<sub>2</sub>O<sub>3</sub> form in both C- and S-samples, which, nevertheless, show a different multiplet splitting and a different energy separation. The latter equals 7.4 eV in the S-Fe<sub>2</sub>O<sub>3</sub> and 8.4 eV in the C-Fe<sub>2</sub>O<sub>3</sub>, with the higher value being indicative for the presence of Fe(OH)<sub>3</sub> [45]. From the data above, one can conclude that S-samples are more reliable than commercial ones.

In mixed metal oxides samples, the surface composition (atomic percentage) was obtained through quantification from the single high resolution XPS spectra for specific peaks: C1s, O1s, and Cu2p<sub>3/2</sub> elements were detected in all samples. Table 2 accounts for atomic percentage concentration data, which are specific for surface composition and can thus differ from those measured by EDX, which are instead relative to bulk concentration. By comparison with data in Table 1, a higher Cu atoms occurrence at the surface is observed for all samples, except for the CP-Cu/Fe-2 sample.

**Table 2.** Surface composition in mixed oxide samples determined by XPS. Atomic percentages are reported as mean values ± 1S (values averaged out of at least three replicates).

Sample	Surface Content (at. %)					Metal Content Ratio	
	C	O	Cu	In	Fe	Cu/In	Cu/Fe
HEM-Cu/In-2	42 ± 7	39.1 ± 0.7	13 ± 5	7 ± 2	-	1.95 ± 0.20	-
CP-Cu/In-2	26 ± 3	42.8 ± 1.0	17.4 ± 0.9	13.5 ± 1.2	-	1.29 ± 0.06	-
HEM-Cu/Fe-2	40.0 ± 0.5	36.4 ± 0.5	13.9 ± 0.2	-	9.7 ± 0.2	-	1.47 ± 0.12
CP-Cu/Fe-2	31.3 ± 1.0	45.8 ± 1.5	9.2 ± 0.2	-	14 ± 2	-	0.68 ± 0.13

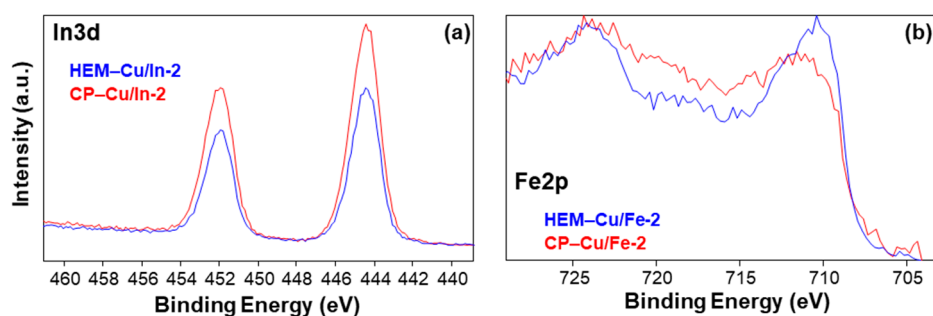
High resolution spectra for Cu speciation in mixed metal oxides samples are shown in Figure 1. By comparing samples prepared by HEM (Figure 1a,b) or CP (Figure 1c,d), a nearly perfect trace overlapping is observed in both Cu/In and Cu/Fe pairs, showing no difference for the preparation techniques.



**Figure 1.** X-ray Photoelectron spectra for Cu  $2p_{3/2}$  and Cu  $L_{3}M_{4,5}M_{4,5}$  (Cu LMM) Auger transition in (a,b) Cu/In and in (c,d) Cu/Fe pairs.

Moreover, Cu atoms on the surface are exclusively encountered as Cu(I), with a CuO component that is observed only in traces and not quantifiable [42]. This is true also for samples prepared using commercial- $\text{Cu}_2\text{O}$ , which contains 30% CuO (*vide infra*), showing that, where present, Cu(II) is in the bulk more than on the surface.

The spectra for In-3d core level doublet were recorded in HEM and CP mixed oxides samples and they are shown in Figure 2a: the only chemical state observed was  $\text{In}_2\text{O}_3$  [43,44]. Figure 2b shows the Fe 2p core level spectra as recorded in mixed oxides samples. Curve fitting results and peak analysis show the presence of the solely  $\alpha\text{-Fe}_2\text{O}_3$  form of iron species [45,46] in both measured samples.



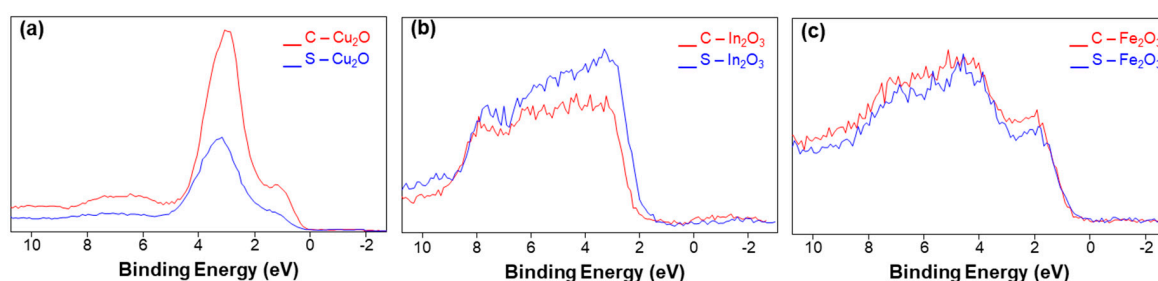
**Figure 2.** XP spectra for (a) In 3d and (b) Fe 2p core levels in mixed metal oxides samples.

In conclusion, samples prepared by HEM and CP do not show differences for what concerns the surface composition, and more interestingly C- and S-samples of ternary oxides show very similar surface composition and properties, even if C- $\text{Cu}_2\text{O}$  contains 30% of Cu(II) which remains confined in the bulk.

#### Valence Band Maximum Evaluation by XPS

XPS analysis can be used to measure Valence Band Maximum (VBM) energy level, which is fundamental for subsequent band structure evaluation. This task can be accomplished adopting the procedure developed by Kraut and co-workers [47,48], then correctly extended to not covalent and oxide-based semiconductors by Chambers and co-workers [49]. The procedure requires acquisition

of the XP spectrum in the low binding energy region, near the zero-value which corresponds to the Fermi level. Here, the XP spectrum reflects the electron density in the low energy states [47–49]. The VBM energy is determined as the intersection of two straight lines, obtained from least square fitting: the first line fits the spectrum baseline and background over the Fermi level, the second line fits the leading edge of the spectrum towards increasing binding energy [49]. In this work, while the band edge fitting operation was optimized through the maximization of  $R^2$  correlation coefficient, the background fitting operation was performed by inclusion of all data points measured at negative binding energies coordinates. Figure 3 shows XP spectra in the Valence Band region, between 11 and -3 eV, with comparison of Commercial and Synthesized binary metal oxide samples. In  $\text{Cu}_2\text{O}$  samples, a  $0.74 \pm 0.20$  eV difference in extracted band edges is observed, though spectra are similar in shape and sharp steep band edges do appear. Spectra are shown in Figure 3a with values equal  $1.65 \pm 0.20$  and  $0.86 \pm 0.14$  eV in C- $\text{Cu}_2\text{O}$  and S- $\text{Cu}_2\text{O}$  samples, respectively, the difference being ascribed to the presence of  $\text{CuO}$  in the C-sample, for which a more positive VB edge is commonly attested [19,40,50]. Results agree with both theoretical [40,51] and experimental common literature references [19,20,50,52].



**Figure 3.** XP Valence Band Spectra in (a)  $\text{Cu}_2\text{O}$ , (b)  $\text{In}_2\text{O}_3$ , and (c)  $\text{Fe}_2\text{O}_3$  binary oxide samples.

XP spectra for valence band region in  $\text{In}_2\text{O}_3$  samples are shown in Figure 3b, where a certain difference is observed: the synthesized sample shows a higher intensity peak than the commercial one. This feature is indicative of a higher number of localized electrons within the VB energy levels, and its origin has been identified in the occurrence of random O-vacancies, whose levels build up the VB ones by orbital mixing [53], and in the crystalline domains size. This last could result reduced enough to hinder efficient electron transfer to the CB and so decrease the naturally occurring *n*-type character of this semiconductor material [25,54]: in fact, VBM results are closer to the Fermi level. Extracted values equal  $2.20 \pm 0.11$  and  $1.80 \pm 0.15$  eV for Commercial and Synthesized samples respectively, and both result less positive than literature values [25,30,34,52], making the material closer to hydrogen evolution potential.

Figure 3c reports XP spectra for valence band region in  $\text{Fe}_2\text{O}_3$  samples, and differences between samples are visible, similar to those observed in  $\text{In}_2\text{O}_3$  samples. In this case, the Commercial sample is characterized by a higher number of electrons in the VB, supposed to derive from localized states within the energy gap, due to defective particles, especially oxygen vacancies [55], and agree with the presence of iron hydroxide traces shown by XPS speciation measurements.

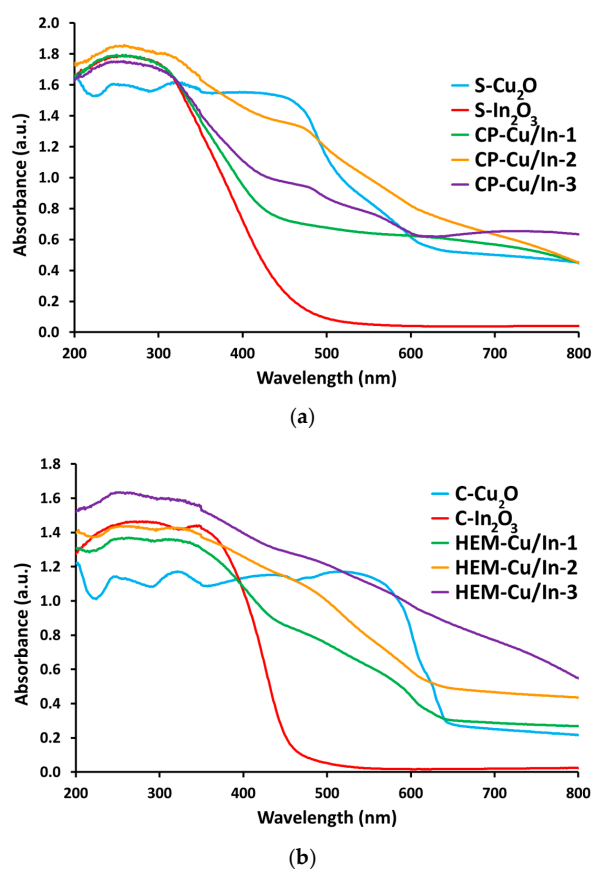
A less intense signal is recorded in the synthesized sample, and it is thought to be caused by defective particles and small crystalline domains. XPS data for Fe-containing systems are typically difficult to fit/convolve. Extracted VBM position are  $1.53 \pm 0.22$  and  $1.67 \pm 0.23$  eV for C- $\text{Fe}_2\text{O}_3$  and S- $\text{Fe}_2\text{O}_3$  samples, respectively, with a small difference between them and at lower energy than some literature theoretical [55,56] and experimental data [36,39,57]. Table 3 lists VBM extracted values for all binary metal oxide samples described above.

**Table 3.** Valence Band Maxima extracted from XPS measurements. The error values were determined from the regression method extrapolation.

Sample	VBM (eV)	Sample	VBM (eV)
C-Cu <sub>2</sub> O	1.65 ± 0.20	S-Cu <sub>2</sub> O	0.86 ± 0.14
C-In <sub>2</sub> O <sub>3</sub>	2.20 ± 0.11	S-In <sub>2</sub> O <sub>3</sub>	1.80 ± 0.15
C-Fe <sub>2</sub> O <sub>3</sub>	1.53 ± 0.22	S-Fe <sub>2</sub> O <sub>3</sub>	1.67 ± 0.23

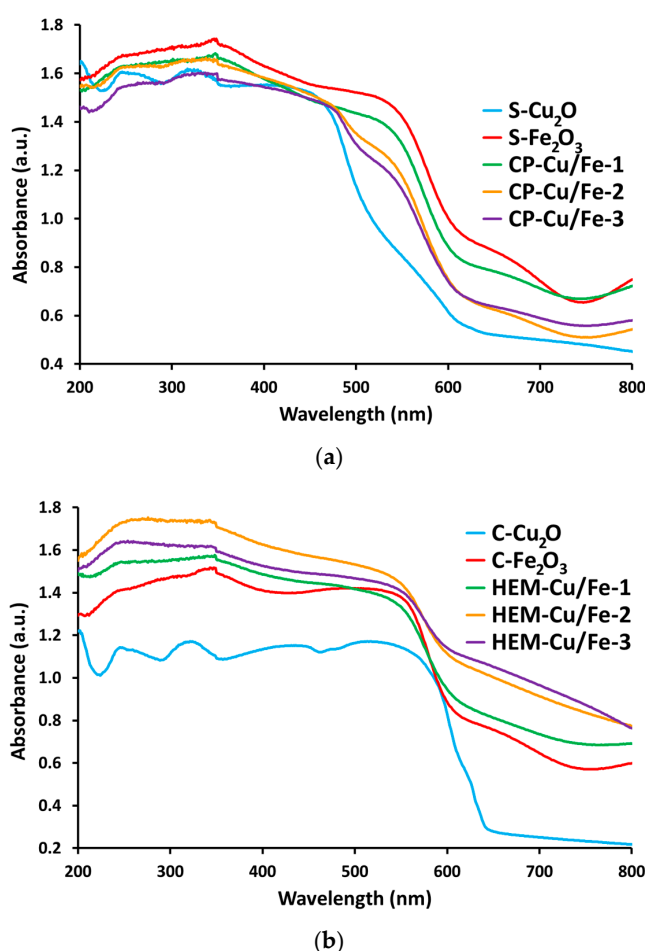
### 2.3. UV-Visible Spectroscopy Characterization

The first step for photocatalytic processes is light absorption, thus UV-Visible Diffuse Reflectance Spectroscopy (UV-VIS DRS) was used to measure the optical properties for all samples in 200–800 nm range. The UV-VIS DRS properties directly depend on band gap and electronic energy structure and they affect the photocatalytic activity too [10,11,18]. Changes of light absorption properties with composition were observed in mixed oxide samples in present work. In samples containing the Cu<sub>2</sub>O/In<sub>2</sub>O<sub>3</sub> pair, absorption spectra (Figure 4) clearly change with composition. Lines corresponding to binary metal oxides are plotted for comparison. Whether HEM or CP preparation technique is adopted, the increase in Cu/In ratio induces a general redshift in absorption spectra and a corresponding significant absorption at wavelengths above 500 nm, where fundamental transition of Cu<sub>2</sub>O is [19]. While the absorption tail observed in CP prepared samples (Figure 4a) can be attributed mainly to scattering phenomena, due to aggregation of small particle size, the reduction in size for Cu<sub>2</sub>O component is at the origin of the blueshift observed in spectra of HEM prepared samples (Figure 4b). Such a shift and the marked absorption tails observed at long wavelengths for samples prepared using C-Cu<sub>2</sub>O are instead attributed to the not negligible CuO presence in commercial Cu<sub>2</sub>O, because CuO fundamental absorption occurs at lower energy [19].



**Figure 4.** UV-Visible Diffuse Reflectance Spectroscopy (UV-VIS DRS) for Cu/In mixed oxides pairs prepared by (a) CP and by (b) HEM.

Absorption spectra recorded for samples containing the  $\text{Cu}_2\text{O}/\text{Fe}_2\text{O}_3$  pair are shown in Figure 5, together with lines of binary metal oxides for comparison. Here, the increase in Cu/Fe is found to change absorption spectra for both preparation techniques, but in a different way accounting for absorption features of the two components at wavelengths longer than 500 nm [19,26]. In CP prepared samples (Figure 5a) the component oxides present fundamental absorption region different enough to observe a linear trend with increasing Cu/Fe ratio and thus a slight blueshift and increasing similarity towards the  $\text{Cu}_2\text{O}$  spectrum. This feature has been attributed to typical  $\alpha\text{-Fe}_2\text{O}_3$  spectra characteristics which appear over 550 nm [26,55], well over than S- $\text{Cu}_2\text{O}$  fundamental absorption [19], thus, the addition of this specific component did not result in a redshift. On the contrary, in samples prepared by HEM using C- $\text{Cu}_2\text{O}$  (Figure 5b), spectra of precursor components (C- $\text{Cu}_2\text{O}$  and C- $\text{Fe}_2\text{O}_3$ ) show a similar fundamental absorption region and differences only in absorption intensity. Hence, an increase in Cu/Fe ratio corresponds to a higher absorption at longer wavelengths, which has been mainly attributed to CuO impurities in C- $\text{Cu}_2\text{O}$  precursor.



**Figure 5.** UV-Visible DRS for Cu/Fe mixed oxides pairs prepared by (a) CP and by (b) HEM.

However, DRS absorption measurements demonstrated that prepared nanocomposites are photoactive in almost the whole UV-Visible range in function of their composition. In particular, the introduction of  $\text{Cu}_2\text{O}$  has given  $\text{In}_2\text{O}_3$  a better response in the VIS-region, while the interaction between  $\text{Cu}_2\text{O}$  and  $\alpha\text{-Fe}_2\text{O}_3$  has induced less predictable effects because of similar fundamental absorption. Studying these features is crucial because they are involved in enhancement of solar light harvesting properties for application in photocatalysis. Anyway, in both pairs, properties are very sensitive to nanocomposites preparation procedures, and thermal treatments.



### Band-Gap Evaluation by UV-Visible Spectroscopy

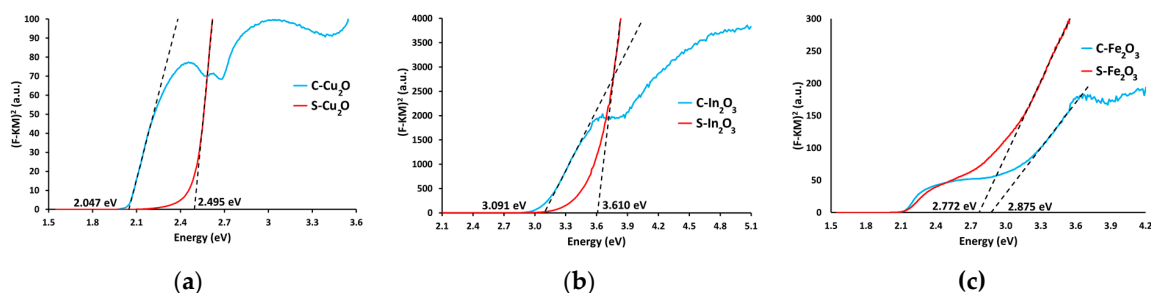
The optical energy gap ( $E_{g,opt}$ ) is a fundamental property in semiconductors and it equals the minimum energy required to excite an electron from VB to CB by means of light absorption. This energy gap can be directly measured through UV-Visible spectroscopy, if a single fundamental absorption is clearly distinguished. In case this is not possible or solid-state samples are studied, as in the present work, a simple and widely adopted data elaboration method can be used, which is described in detail elsewhere [58,59]. Briefly, the Kubelka–Munk function (K–M),  $F(R)$ , is calculated starting from the experimental reflectance spectrum and is related to linear absorption coefficient  $\alpha$  and to  $E_{g,opt}$  through a power law describing the optical absorption strength in function of photon energy.

$$F(R) \cdot (h\nu) = A \cdot (h\nu - E_g)^n \quad (1)$$

The exponent  $n$  assumes different values depending on the type of electronic transition. Provided there is some knowledge about the occurring electronic transition, the plot of product versus radiation energy,  $(h\nu)$ , shows up a linear trend in the region corresponding to fundamental absorption and energy gap [58,59].

$$(F(R) \cdot (h\nu))^{1/n} \quad (2)$$

The linear least square fitting in this region allows for the extraction of the  $E_{g,opt}$  value as the intersection of straight line with the energy axis, according to the Tauc Plot extrapolation procedure. It can be applied to pure or lightly doped semiconductors, but it does not produce reliable results if fundamental absorption edges are not separable or if a simple combination of individual optical gaps cannot be assumed, as in highly doped semiconductors or in nanocomposites. In the present work, mixed oxide samples fall in the second case, therefore  $E_{g,opt}$  value was measured only for all single metal oxide samples. The linear regression operations have been optimized by merging two criteria: (a) maximization of correlation coefficient  $R^2$ , ensuring a better description by linear model and (b) consideration of a calculation range containing a minimum of 20 data points, to give procedure a statistical validation. Matching those two criteria allows for a good extrapolation result. Tauc Plots for different single metal oxide samples are shown in Figure 6.



**Figure 6.** Tauc Plots for (a)  $\text{Cu}_2\text{O}$ , (b)  $\text{In}_2\text{O}_3$ , and (c)  $\text{Fe}_2\text{O}_3$  binary oxide samples.

In the case of  $\text{Cu}_2\text{O}$ , absorption spectra are reported as light blue traces in both Figures 4 and 5 and large difference do appear between C- $\text{Cu}_2\text{O}$  and S- $\text{Cu}_2\text{O}$  samples. Absorption in the commercial sample extends up to 600 nm, while the S- $\text{Cu}_2\text{O}$  sample shows a significant absorption in the UV region, decreasing significantly over 500 nm, where some absorption is guaranteed by a pronounced tail extending at longer wavelengths. The extended presence of CuO (30%) in the commercial precursor and particle size cause the differences. Figure 6a shows Tauc Plots for Cu-oxide samples. These show a steeper rise for S- $\text{Cu}_2\text{O}$  sample and two very different values for estimated  $E_{g,opt}$  energies are observed, and both have been calculated assuming a direct allowed electronic transition occurs between VBM and CBM [19,40], and  $n$  coefficient is, thus, set equal to 0.5. Values within 2.0 and 2.2 eV are generally attested in literature for  $\text{Cu}_2\text{O}$  [40], though quantum size effect is widely recognized able to markedly influence its energy gap. In this work,  $E_{g,opt}$  values equal to 2.047 and 2.495 eV for C- $\text{Cu}_2\text{O}$  and

S-Cu<sub>2</sub>O sample, respectively, are found in accordance with literature [20,36,39]. This is also true for the synthesized sample, where a UV-shifted value is justified by quantum size confinement and where a pronounced tail, recorded before gap and reflected in absorption spectrum, is attributed to crystalline disorder and broad size dispersion.

Absorption spectra for In<sub>2</sub>O<sub>3</sub> samples are shown in Figure 4 as red traces which do not show large differences at a first examination: both commercial and synthesized samples absorb radiation mainly in the near UV range (below 450 nm). Tauc Plots (Figure 6b) enhance features previously not evident, such as a large tail in the S-In<sub>2</sub>O<sub>3</sub> trace or its steeper rise with respect to the C-In<sub>2</sub>O<sub>3</sub>. Extracted  $E_{g,opt}$  values are equal to 3.091 eV in C-In<sub>2</sub>O<sub>3</sub> and to 3.610 eV in the S-In<sub>2</sub>O<sub>3</sub> sample. The determination was performed considering that a direct allowed electronic transition occurs, as for recent studies [25,54]. Though band gap nature and electronic structure for In<sub>2</sub>O<sub>3</sub> are somewhat controversial, a fundamental band gap ranging from 2.6 to 2.9 eV is now commonly accepted [25], and it slightly differs from the optical gap, attested within 2.3 and 3.8 eV [30,34], therefore values measured in the present work result in accordance with literature. The 0.6 eV difference observed has been deemed coming from the preparation technique. In this case, its contribution affects band structure mainly through the introduction of lattice defects, especially oxygen vacancies, and creation of mid-gap states, a phenomenon which is commonly found in *n*-type wide gap semiconductor oxides [54], the effect appears more pronounced in the S-In<sub>2</sub>O<sub>3</sub> sample, where the trace shows a large tail extending towards low energies.

Both the Fe<sub>2</sub>O<sub>3</sub> samples exhibit good light harvesting properties in the whole UV-Visible region, with significant absorption up to 600 nm, higher in S-Fe<sub>2</sub>O<sub>3</sub> sample, as shown by analysis of red traces in Figure 5. Four different regions are commonly identified in absorption spectra [31] and the fundamental band gap is recognized at 2.2 eV [26,55], with discussion whether its direct or indirect nature and thus its coincidence with the optical band gap. Furthermore, complication can arise in  $E_{g,opt}$  determination because it usually merges with an exciton absorption, which is produced by an indirect transition between 3d–3d orbitals and dominates spectra over 550 nm, giving hematite its typical red color [55]. The exciton is clearly observed in Tauc Plots as the low intensity shoulder with onset at 2.1 eV (Figure 6c). Because of this indirect nature, absorption below 2.1–2.2 eV is considered not able to produce useful separated electron-hole pairs, suffering from very fast recombination, a widely recognized drawback in  $\alpha$ -Fe<sub>2</sub>O<sub>3</sub> [26,55]. Therefore, to study photocatalysis-useful optical absorption, a direct allowed transition has been assumed for Tauc Plots. Extracted  $E_{g,opt}$  equal 2.772 and 2.875 eV for S-Fe<sub>2</sub>O<sub>3</sub> and C-Fe<sub>2</sub>O<sub>3</sub> sample, respectively. Although these values result unusually larger than the commonly accepted and measured ones [31,32,36,39], such a discrepancy can be explained by peculiar interacting electronic levels in iron atoms and presence of lattice defective particles. All these elements can lead to mixing between the standard direct gap and higher energy features (Ligand to Metal Charge Transfer (LMCT) processes occurring at 2.9–3.1 eV) [55]. Aggregation of very small particles towards polycrystalline clusters formation was cited able to enhance this mixing and can be also identified as the source for the large tailing trend in S-Fe<sub>2</sub>O<sub>3</sub> trace.

Table 4 lists single metal oxide samples, with indication of optical energy gap extracted values and corresponding absorption wavelength. Except for iron oxide, S-samples show higher optical energy gaps than C-ones. Moreover, S-samples reveal a tailing trend more pronounced than in C-samples, indicative of broader size dispersion and lower average size (10–50 nm).

**Table 4.** Optical energy gap and corresponding absorption wavelength in binary oxide samples.

Sample	Optical $E_g$ (eV)	Absorption Wavelength <sup>1</sup> (nm)
C-Cu <sub>2</sub> O	2.047	605.7
S-Cu <sub>2</sub> O	2.495	497.0
C-In <sub>2</sub> O <sub>3</sub>	3.091	401.1
S-In <sub>2</sub> O <sub>3</sub>	3.610	337.9
C-Fe <sub>2</sub> O <sub>3</sub>	2.875	431.3
S-Fe <sub>2</sub> O <sub>3</sub>	2.772	447.3

<sup>1</sup> Calculated by the relation  $\lambda = 1240/E_{g,opt}$  [18].

#### 2.4. Band Structure Evaluation and Discussion

Possible photocatalytic activity performances in solar fuels production by utilization of ternary metal oxides prepared in this work has been outlined on the basis of electronic band structure of binary and ternary mixed metal oxides samples. In fact, the energy position of band edges corresponds to redox potential of electrons and holes in semiconductor materials, thus it determines the redox behavior of photogenerated charge carriers and their possible transfer to adsorbed chemical species, as needed for photocatalytic reaction to occur [6,7,10,11].

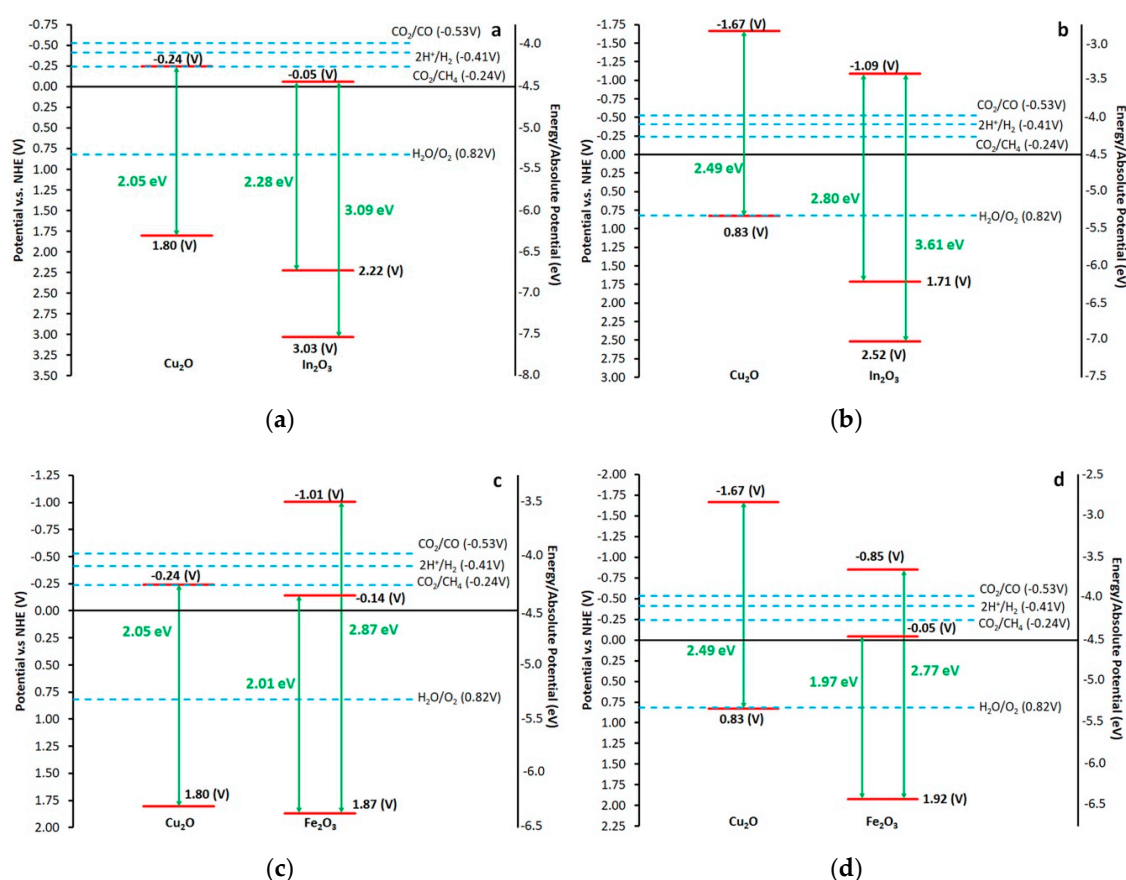
An estimation for VBM and CBM is thus fundamental in characterization of semiconductors, and this task is usually accomplished by combination of theoretical considerations and of experimental data obtained by use of different techniques [10–12]. For energy band structure evaluation in the present work, experimental data for VB edges, as determined by XPS, and for  $E_{g,opt}$ , as determined by UV-Visible DRS, have been used in combination with theoretical arguments, found in literature, about energy band structure of specific semiconductor metal oxide considered. Band structures plots are shown in Figure 7 for ternary metal oxides, and they are reported as composed by those of binary metal oxides and compared to redox potentials involved in solar fuels production [2,11].

In all band structure schemes (Figure 7), the left side is refers to Cu<sub>2</sub>O energy bands, both for C- and S-samples. These were determined by considering only VBM and  $E_{g,opt}$ , where this last equals the fundamental  $E_g$  [19]. A big discrepancy observed in energy gap values and band position has been ascribed to CuO impurities, which were detected in C-samples used as precursor for HEM, and to quantum size confinement effect. Both of these arguments concur to the whole S-Cu<sub>2</sub>O sample structure being moved upward in energy with respect to the C-Cu<sub>2</sub>O sample, for which a different plot for Cu<sub>2</sub>O and CuO is not possible. Moreover, it is worth noting that both CuO and Cu<sub>2</sub>O are *p-type* semiconductor materials [19,50], but the unpredictable formation of junctions between Cu<sub>2</sub>O and CuO can affect the Fermi level position in C-Cu<sub>2</sub>O [50], thus hiding the *p-type* character expected in the schemes of Figure 7a,c, which is on the contrary easily detectable in schemes of Figure 7b,d, referred to S-Cu<sub>2</sub>O.

Band structures schemes for C-In<sub>2</sub>O<sub>3</sub> and S-In<sub>2</sub>O<sub>3</sub> samples are reported in Figure 7a,b, respectively, where theoretical arguments found in literature about somewhat controversial and long debated electronic structure were considered [25]. In this frame, the direct optical gap measured involves a level which lays 0.81 eV below the VBM determined by XPS. Thus, the fundamental  $E_g$  for In<sub>2</sub>O<sub>3</sub> equals 2.28 and 2.80 eV for C-In<sub>2</sub>O<sub>3</sub> and S-In<sub>2</sub>O<sub>3</sub> samples, respectively, in accordance with a maximum possible 2.9 eV value [25]. Also, schemes report correct *n-type* semiconductor behavior in both the samples [25,54].

In the case of Fe<sub>2</sub>O<sub>3</sub> samples, band structure schemes are plotted in Figure 7c,d for C-Fe<sub>2</sub>O<sub>3</sub> and S-Fe<sub>2</sub>O<sub>3</sub> samples, respectively. While optical energy gap is considered to occur between the VBM determined by XPS and a level above the CBM, the fundamental energy gap involving the real CBM equals the energy required for exciton formation [55]. This energy has been measured by studying the corresponding optical absorption with Tauc Plot procedure, with assumption of an indirect transition (*n* equals 2) which incorporates exciton absorption and thus reflects the interested energy difference [31]. Fundamental  $E_g$  equals 2.01 and 1.97 eV for C-Fe<sub>2</sub>O<sub>3</sub> and S-Fe<sub>2</sub>O<sub>3</sub> samples, respectively, values slightly

lower than common 2.1 eV expected for exciton in hematite [55]. As for the  $\text{In}_2\text{O}_3$  samples, expected *n*-type semiconductor character results evident in all  $\alpha\text{-Fe}_2\text{O}_3$  samples [26,55].



**Figure 7.** Band structures schemes for  $\text{Cu}_2\text{O}/\text{In}_2\text{O}_3$  pair, prepared by (a) HEM and (b) CP, and for  $\text{Cu}_2\text{O}/\text{Fe}_2\text{O}_3$  pair, prepared by (c) HEM and (d) CP.

Results obtained by this method are shown in Table 5, where band edges and energy gaps, both optical and fundamental are pointed out.

**Table 5.** Resume of energy gaps and band edges levels in semiconductor metal oxides.

Sample	$E_g$ (eV)		VBM (eV)	CBM (eV)
	Fundamental	Optical		
C- $\text{Cu}_2\text{O}$	2.05	2.05	1.80	-0.24
S- $\text{Cu}_2\text{O}$	2.49	2.49	0.83	-1.67
C- $\text{In}_2\text{O}_3$	2.28	3.09	2.22	-0.05
S- $\text{In}_2\text{O}_3$	2.80	3.61	1.71	-1.09
C- $\text{Fe}_2\text{O}_3$	2.01	2.87	1.87	-0.14
S- $\text{Fe}_2\text{O}_3$	1.97	2.77	1.92	-0.05

From data in Table 5, some photocatalytic activity result in solar fuels production can be expected only for the CP prepared  $\text{Cu}_2\text{O}/\text{In}_2\text{O}_3$  samples, whose band scheme structure is shown in Figure 7b. This pair could reveal useful in  $\text{H}_2$  generation coming from photocatalytic water splitting, a reaction in which it is able to participate thank to proper band levels alignment of two metal oxide components. In particular, electrons excited in  $\text{Cu}_2\text{O}$  can move into  $\text{In}_2\text{O}_3$  CB and leave behind holes in VB, a level adequate to oxidize water molecules. At the same time, the electrons photogenerated in  $\text{In}_2\text{O}_3$  are in a level adequate to reduce  $\text{H}^+$  and produce  $\text{H}_2$ , and this level also collects electrons coming from  $\text{Cu}_2\text{O}$

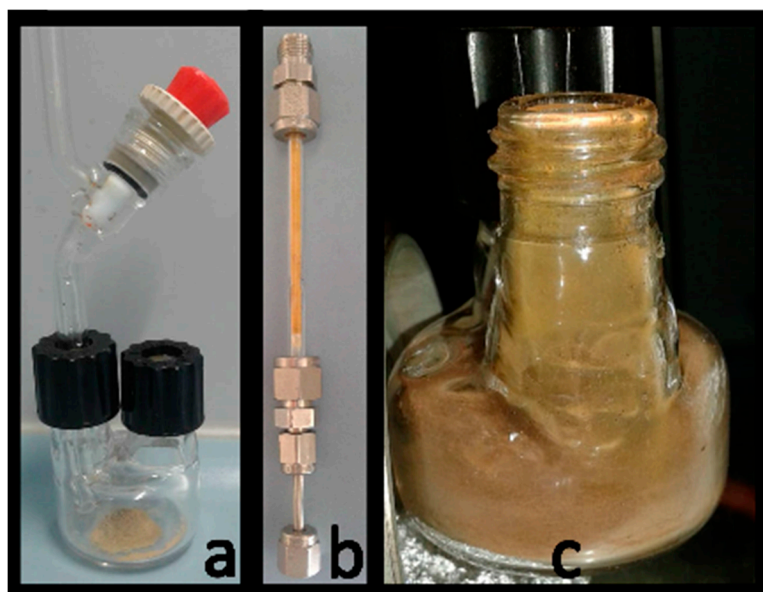
CB, while the photogenerated holes move into  $\text{Cu}_2\text{O}$  VB, where they can oxidize water molecules. On the other hand, large charge carrier recombination occurring in  $\text{Cu}_2\text{O}$  could be responsible for widely recognized poor activity in general.

At the same time,  $\text{CO}_2$  reduction can show different trend whether a  $1e^-$  or multielectron-transfer is considered. In fact, the CB potential of the two components, results not negative enough for one electron transfer to  $\text{CO}_2$  molecule ( $-1.90$  V vs. NHE is needed) [2]. As a matter of fact, this is not the reaction we are considering: the Proton Coupled Electron Transfer (PCET) is the process that should operate in the present case.

On the basis of similar considerations, poor activity for solar fuels production can be foreseen for other oxides pairs studied in the present work which do not provide the potential for one-electron transfer to  $\text{CO}_2$  molecule and do not show a proper level alignment for water splitting. Additionally, the presence of  $\text{CuO}$  impurities can be at the origin of enhanced charge carrier recombination, a phenomenon recognized in this material, up to withdrawn all photogenerated charge carriers from reaction or charge carrier separation processes. More, in both  $\text{Cu}_2\text{O}/\text{Fe}_2\text{O}_3$  pairs (Figure 7c,d), the not proper level alignment adds to their relative positions, which results not adequate for photogenerated charge carrier separation, as in HEM prepared pair (Figure 7c), or even in enhanced interband recombination, as in CP prepared pair (Figure 7d).

### 2.5. Photocatalytic Activity

Therefore, among all materials prepared in this work, only CP- $\text{Cu}_2\text{O}/\text{In}_2\text{O}_3$  was tested in  $\text{CO}_2$ - $\text{H}_2\text{O}$  coprocessing, according to procedure described in Methods section, as reputed the only one able to carry out the redox process. Three different reactors were used for running the reaction, all under Xe-lamp irradiation (Figure 8).



**Figure 8.** Reactors used for running the photochemical reaction. (a) Bulk nano-sized catalyst in a batch-reactor. (b) Flow-reactor loaded with bulk nano-catalyst. (c) Nano-sized catalyst finely dispersed on the wall of the reactor, simulating a nano-film.

When reactor (a) or (c) was used, the reaction gas was sampled with a gas-syringe, and with reactor (b) the gas was directly injected into the GC-column. Hydrogen and reduced species of  $\text{CO}_2$  were monitored at regular intervals of time up to 6 h. (see Figure S2 in Supplementary Materials) Table 6 gives the results for the reactors (a)–(c). Using bulk nano-catalysts, after 3 h of irradiation of a  $\text{H}_2\text{O}$ -saturated  $\text{CO}_2$  stream at 298 K no reduction products were observed. Conversely, when

the nano-catalyst was finely dispersed on the surface of the reactor the same mixture gave positive formation of H<sub>2</sub> and traces of reduced CO<sub>2</sub> species.

**Table 6.** Photocatalytic reaction for three different reactors.

Reaction System	Gaseous Reaction Products		
	H <sub>2</sub>	CO	CH <sub>4</sub>
(a)	–	–	–
(b)	–	–	–
(c)	+++	+	+

Results in Table 6 shift attention towards the fundamental role played by reactor design and reaction setup in carrying out a process difficult as the solar fuel production. It is clearly visible how the catalyst film distribution (reactor c), allowing for a better and more homogeneous light penetration to the photo-active centers with respect to the massive-powdered-material (reactors a,b), allows the reaction to go. In practice, a film-like distribution of the photomaterial is preferred to its bulk packing as the larger surface of the photo-catalyst allows more photons to be active. Most likely, if the illumination system is changed with respect to the one we have used (Xe-lamp), the reactor (b) will be working too. The lesson learned with such synthesis of photo-materials and photocatalytic experiments, prompts us to a more focused approach to photocatalyst development coupled to reactor design and engineering for a more active conversion of CO<sub>2</sub> and water into energy products.

### 3. Materials and Methods

The following reagents were used as received and without any further treatment: Cu<sub>2</sub>O powder (Fluka AG, in Sigma-Aldrich, Steinheim, Germany), In<sub>2</sub>O<sub>3</sub> powder (Sigma-Aldrich, Steinheim, Germany), Fe<sub>2</sub>O<sub>3</sub> powder (Sigma-Aldrich, Steinheim, Germany), anhydrous CuSO<sub>4</sub> (BDH Chemicals Ltd, Poole, England), In(NO<sub>3</sub>)<sub>3</sub>·3H<sub>2</sub>O (Sigma-Aldrich, Steinheim, Germany), FeCl<sub>3</sub> (Carlo Erba Reagents srl, Milano, Italy), NaOH pellets (Fluka AG in Sigma Aldrich, Steinheim, Germany), and L-Ascorbic Acid (Alfa Aesar GmbH, Karlsruhe, Germany). Deionized water was used for all syntheses in which a solvent was required.

#### 3.1. Preparation of Oxides

Single metal oxide samples were prepared by precipitation method, procedures adopted differ upon specific metal oxide. If not differently indicated, all operations were performed at ambient temperature and under air condition.

##### 3.1.1. Cu<sub>2</sub>O

Copper (I) oxide samples were prepared by adding 20 mL of a 0.5 M NaOH aqueous solution, dropwise and under stirring, to 10 mL of a 0.5 M CuSO<sub>4</sub> aqueous solution, thus producing copper (II) hydroxide. An adequate volume of a 0.1 M L-ascorbic acid aqueous solution was added dropwise, in order to reduce the Cu(II)-hydroxide into copper(I) oxide, Cu<sub>2</sub>O. Particles were separated by centrifugation (6000 rpm, 15 min), washed with deionized water, and dried at 80 °C overnight.

##### 3.1.2. In<sub>2</sub>O<sub>3</sub>

To 15 mL of a 1.1 M In(NO<sub>3</sub>)<sub>3</sub>·H<sub>2</sub>O aqueous solution, 50 mL of a 1.2 M NaOH aqueous solution were added dropwise, under stirring. The resulting indium(III) hydroxide suspension was kept under constant stirring for one further hour, then the solid was separated by centrifugation (6000 rpm, 15 min), washed with deionized water, and dried at 80 °C overnight. The dried solid was grinded in a ceramic

mortar and the powder was heated in air at 300 °C for 2 h and then at 400 °C for 1 h, to convert hydroxide into indium(III) oxide,  $\text{In}_2\text{O}_3$ .

### 3.1.3. $\text{Fe}_2\text{O}_3$

Iron (III) oxide was prepared adding drop by drop 50 mL of a 1.2 M NaOH aqueous solution to the same volume of a 0.4 M  $\text{FeCl}_3$  aqueous solution, under stirring. The so prepared suspension contains mixed oxide-hydroxide iron particles, which were separated by centrifugation (6000 rpm, 15 min), washed with deionized water and dried at 80 °C overnight. It was then grinded in a ceramic mortar and heated in air at 450 °C for 1 h, for complete conversion into iron(III) oxide,  $\text{Fe}_2\text{O}_3$ .

### 3.1.4. Preparation of Mixed Oxides by Coprecipitation Using Synthesized Binary Oxides

General Procedure:  $\text{Cu}_2\text{O}$  was deposited on the nanoparticles of the second oxide with formation of core-shell  $\text{In}_2\text{O}_3$  or  $\text{Fe}_2\text{O}_3$  particles covered with  $\text{Cu}_2\text{O}$ . We have attempted to produce  $\text{Cu}_2\text{O}$  core shell covered with  $\text{In}_2\text{O}_3$  or  $\text{Fe}_2\text{O}_3$  but so far substantial oxidation of Cu(I) to Cu(II) was observed during the dehydration of In- or Fe-hydroxides. In 20 mL of a 0.5 M  $\text{CuSO}_4$  aqueous solution, weighted (see below) amounts of the nano-sized powder for the *n-type* partner oxide were dispersed. 40 mL of a 0.5 M NaOH aqueous solution were dropwise added to such solution under stirring. When the addition was completed, an adequate amount of a 0.1 M L-ascorbic acid aqueous solution was added dropwise as a reductant (glucose has also been used, but with lower yield) to produce  $\text{Cu}_2\text{O}$  that deposited on the *n-type* semiconductor. Particles were separated by centrifugation (6000 rpm, 15 min), washed with deionized water, and dried at 80 °C overnight.

- (a) 3.5929, 1.5698, and 0.8121 g of S- $\text{In}_2\text{O}_3$  nano-powder were dispersed in  $\text{CuSO}_4$  aqueous solution for the ratios Cu/In-1, 2, and 3, respectively, and treated as reported above.
- (b) 2.1781, 0.8799, and 0.7287 g of S- $\text{Fe}_2\text{O}_3$  powder were dispersed in  $\text{CuSO}_4$  aqueous solution for ratios Cu/Fe-1, 2, and 3, respectively and reacted as reported in the general procedure.

### 3.1.5. Preparation of Mixed Oxides by High Energy Milling-HEM Using Commercial Samples

General Procedure: Mixed oxides were prepared by weighting defined quantities of commercial metal oxides powders and pouring them in cylindrical agate jars (46 mL), together with 3 agate spheres, 1 cm in diameter. Jars were sealed and placed in a planetary mill (Pulverisette 7-Fritsch, GmbH, Idar-Oberstein, Germany) and subjected to two cycles at 800 rpm, each with a duration of 90 min.

- (a) for Cu/In-1, 0.5469 g of C- $\text{Cu}_2\text{O}$  and 1.9863 g of C- $\text{In}_2\text{O}_3$  were mixed.
- (b) for Cu/In-2, 0.8579 g of C- $\text{Cu}_2\text{O}$  and 1.6354 g of C- $\text{In}_2\text{O}_3$  were mixed.
- (c) for Cu/In-3, 1.2705 g of C- $\text{Cu}_2\text{O}$  and 1.2304 g of C- $\text{In}_2\text{O}_3$  were mixed.
- (d) For Cu/Fe-1, 0.7740 g of C- $\text{Cu}_2\text{O}$  and 1.7332 g of C- $\text{Fe}_2\text{O}_3$  were mixed.
- (e) For Cu/Fe-2, 1.4252 g of C- $\text{Cu}_2\text{O}$  and 1.5915 g of C- $\text{Fe}_2\text{O}_3$  were mixed.
- (f) For Cu/Fe-3, 1.6086 g of C- $\text{Cu}_2\text{O}$  and 0.8969 g of C- $\text{Fe}_2\text{O}_3$  were mixed.

## 3.2. Characterization

Powder materials composition was determined by EDX measurements using an EDX-720 Shimadzu Spectrometer (Shimadzu Europe GmbH, Duisburg, Germany).

UV-Visible DRS spectra were recorded in the 200–800 nm region with a Cary-5000 spectrophotometer (Agilent Technologies, Santa Clara, CA, United States), equipped with an integration sphere covered by polymer internal coating, with a standard sample of the same material and with sample-holder for powder material.

X-ray Photoelectron Spectroscopy (XPS) analyses were run on a PHI 5000 Versa Probe II Scanning XPS Microprobe spectrometer (ULVAC-PHI Inc., Kanagawa, Japan). The measurements were done with a monochromatised Al  $K\alpha$  source (X-ray spot 200  $\mu\text{m}$ ), at a power of 50.3 W. Wide scans and

detailed spectra were acquired in Fixed Analyzer Transmission (FAT) mode with a pass energy of 117.40 eV and 29.35 eV, respectively. An electron gun was used for charge compensation (1.0 V 20.0  $\mu$ A). Data processing was performed by using the MultiPak software v. 9.9.0.8.

Gas mixtures were analyzed using a GC (Thermo Scientific Focus GC), equipped with a SUPELCO Carboxen™ 1010 PLOT (30 m  $\times$  0.32 mm) and with a TCD detector.

A 150 W Xe XBO lamp (Osram) was used as source of light for irradiation.

### 3.3. Photocatalytic Activity

Materials activity in solar fuels production was evaluated by using three different reactor systems (Figure 8) fed with a reagent gas mixture composed of CO<sub>2</sub> bubbled in deionized water to saturation. Such gas stream was flown for some minutes through the reactors during their loading operation in order to blow air away. Samples of gas were analyzed at regular intervals of time (30 min) over a period of 3–6 h.

In case (a), 0.1 g of nano-sized photocatalyst was placed in a 40 mL glass reactor, provided with two openings closed by hollow plastic caps. One cap holds a glass tube with a three-way valve for reagent gas mixture loading, the other is provided with a rubber septum for gas sampling using a 250  $\mu$ L gas-tight syringe. The reactor was loaded with 0.15 MPa of CO<sub>2</sub> saturated with H<sub>2</sub>O and stirred under illumination for 3 h. A gas-sample was withdrawn and analyzed using a GC.

In case (b), CO<sub>2</sub> saturated with water at 298 K was flown through a 2 mm i.d. tube (equipped with valves for feeding, sampling and reactor closing and filled with the same nanosized-catalyst) at a rate of 0.1 mL/min under illumination and recycled using a micropump. After three hours cycling the gas was injected into a GC. Alternatively, the tube was filled with CO<sub>2</sub>–H<sub>2</sub>O and the closed system illuminated for 3–6 h. The gas was then injected into the GC column.

In case (c), 0.1 g of the nanosized photocatalyst were dispersed on the internal surface of the same vessel used in (a) using a suspension of the catalyst in a volatile liquid (acetone or pentane) that was then slowly evaporated by flowing N<sub>2</sub>. A thin, homogeneous solid film remained adherent to the surface of the reactor that was charged with CO<sub>2</sub>–H<sub>2</sub>O and illuminated. Illumination was applied for 3–6 h and a sample of gas was withdrawn with the gas-syringe at fixed intervals of time and analyzed by GC.

## 4. Conclusions

The experiments carried out in this work have confirmed that the properties of photocatalysts based on mixed oxides strongly depend on the starting materials and the way the binary- and mixed-oxides are prepared. Even their real composition depends on the technique used for their preparation. Careful analyses are necessary to confirm their composition that can or cannot match the stoichiometric ratio used in their preparation. The surface composition can be different from bulk and this can influence the reactions, should they occur on the surface or into channels in the bulk.

The electronic properties of the photo-materials change with their composition and mode of synthesis. Using two different techniques (HEM and CP), the fundamental properties of the photocatalysts have been measured, including the band-gap and electrochemical potential. Some of the catalysts prepared, based on their band gap and value of E, have been tested in the gas-phase photoreduction of CO<sub>2</sub> + H<sub>2</sub>O. The experimental results show that the synthetic technique influences the photoactivity of the materials that can correctly be foreseen on the basis of bandgap experimentally derived. Of the mixed oxides prepared and described in this work, only Cu<sub>2</sub>O@In<sub>2</sub>O<sub>3</sub> prepared by co-precipitation from synthesized binary oxides have shown positive results in CO<sub>2</sub>–H<sub>2</sub>O photo-processing. Preliminary results show that the composition and synthetic methodologies of mixed-oxides, the reactor geometry, the way of dispersing the photocatalyst sample, play a key role in the light driven reaction of CO<sub>2</sub>–H<sub>2</sub>O. Hydrogen plus reduced species of CO<sub>2</sub> (in lower amount) have been observed, depending on the geometry of the reactor used and the photocatalyst used. In order to observe the formation of reduction products it is necessary that the catalyst is finely dispersed



(thin film) and well illuminated. Massive amounts of photocatalyst are not active, at least under the illumination technique used in this work, most likely because the number of photons that reach the photoactive centers is quite low.

This work is a rare case of full characterization of photo-materials, using UV-Visible DRS, XPS, XRD, TEM, and EDX for the surface and bulk analytical characterization. We show that surface composition may not be the same of the bulk composition and plays a key role in photocatalysts behavior and a full material knowledge is necessary for the correct forecast of their photocatalytic behavior, inferred from experimentally determined bandgaps. Coupling UV-Vis DRS and XPS with EDX is necessary for getting the correct information about the composition of the materials and their surface-bulk characterization. Further studies are planned in order to discover the most active species and the best performing reactor geometry under best illumination conditions, using the systems which gave positive results so far. All of the systems described above are even under evaluation for discovering how their properties are changed with addition of partners such as noble metals or hole scavengers and attribute the correct role to each component of the photomaterial.

**Supplementary Materials:** The followings are available online at <http://www.mdpi.com/2073-4344/10/9/980/s1>, Figure S1: Comparison of CP-Fe<sub>2</sub>O<sub>3</sub> XRD patterns with HEM-Cu/Fe-1 (a) and CP-Cu/Fe-1 (b) along with peak positions for reference diffraction patterns. Figure S2: High resolution XP spectra of all the samples. (a) C-Cu<sub>2</sub>O sample: (a1) Cu 2p<sub>3/2</sub> spectral region, (a2) Cu LMM Auger transition and (a3) O1s spectral region. (b) S-Cu<sub>2</sub>O sample: (b1) Cu2p<sub>3/2</sub> spectral region, (b2) Cu-LMM Auger transition and (b3) O1s spectral region. (c) C-In<sub>2</sub>O<sub>3</sub> sample: (c1) In3d spectral region, (c2) In MNN Auger transition and (c3) O1s spectral region. (d) S-In<sub>2</sub>O<sub>3</sub> sample: (d1) In3d spectral region, (d2) In MNN Auger transition and (d3) O1s spectral region. Fe2p spectral region for (e1) C-Fe<sub>2</sub>O<sub>3</sub> and (e2) S-Fe<sub>2</sub>O<sub>3</sub>. Figure S3: H<sub>2</sub> evolution with time by using CP-Cu/In mixed oxides under VIS light irradiation.

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